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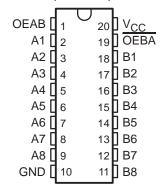
- State-of-the-Art *EPIC-IIB™* BiCMOS Design Significantly Reduces Power Dissipation
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 500 mA Per **JESD 17**
- Typical V_{OLP} (Output Ground Bounce) < 1 V at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$
- High-Drive Outputs (-32-mA IOH, 64-mA IOI)
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), and Plastic (N) and Ceramic (J) DIPs

description

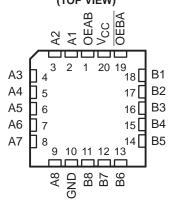
These octal bus transceivers provide for asynchronous communication between data buses. The control-function implementation allows for maximum flexibility in timing. The 'ABT620 devices provide inverted data at the outputs.

These devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic levels at the output-enable (OEAB and OEBA) inputs.

SN54ABT620 . . . J PACKAGE SN74ABT620...DB, DW, N, OR PW PACKAGE (TOP VIEW)



SN54ABT620 . . . FK PACKAGE (TOP VIEW)



The output-enable inputs can be used to disable the device so that the buses are effectively isolated. The dual-enable configuration gives the transceivers the capability of storing data by simultaneously enabling OEAB and OEBA. When both OEAB and OEBA are enabled and all other data sources to the two sets of bus lines are at high impedance, both sets of bus lines (16 total) remain at their last states. In this way, each output reinforces its input in this configuration.

To ensure the high-impedance state during power up or power down, OEBA should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver. OEAB should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The SN54ABT620 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ABT620 is characterized for operation from -40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

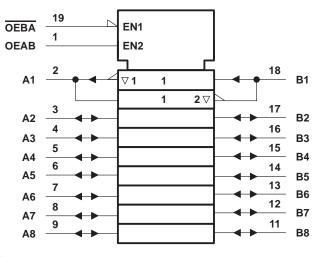
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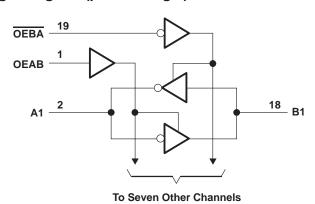
FUNCTION TABLE

INP	UTS	OPERATION				
OEBA	OEAB	OPERATION				
L	L	B data to A bus				
L	Н	B data to A bus, A data to B bus				
Н	L	Isolation				
Н	Н	A data to B bus				

logic symbol†



logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V _{CC}		. -0.5 V to 7 V
Input voltage range, V _I (see Note 1)		. $-0.5 \ V$ to $7 \ V$
Voltage range applied to any output in the high or	power-off state, V _O	-0.5~V to $5.5~V$
Current into any output in the low state, IO: SN54	ABT620	96 mA
SN74	ABT620	128 mA
Input clamp current, I _{IK} (V _I < 0)		–18 mA
Output clamp current, I _{OK} (V _O < 0)		–50 mA
Package thermal impedance, θ_{JA} (see Note 2): D	B package	115°C/W
D	W package	97°C/W
N	I package	67°C/W
P	W package	128°C/W
Storage temperature range, T _{stq}		–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

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recommended operating conditions (see Note 3)

				BT620	SN74ABT620		UNIT
			MIN	MAX	MIN	MAX	UNIT
V _{CC} Supply voltage				5.5	4.5	5.5	V
V _{IH} High-level input voltage		2	FL	2		V	
VIL	V _{IL} Low-level input voltage			0.8		0.8	V
V _I Input voltage		0 <	Vcc	0	VCC	V	
ІОН	IOH High-level output current			-24		-32	mA
loL	DL Low-level output current		200	48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	8	5		5	ns/V
TA	Operating free-air temperature		– 55	125	-40	85	°C

NOTE 3: All unused pins (control or I/O) of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

SN54ABT620, SN74ABT620 OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A = 25°C			SN54ABT620		SN74ABT620		UNIT	
PAI	RAMETER	TEST CONDITIONS		MIN	TYP†	MAX	MIN	MAX	MIN	MAX	UNII	
VIK		V _{CC} = 4.5 V,	I _I = -18 mA			-1.2		-1.2		-1.2	V	
		$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -3 \text{ mA}$	2.5			2.5		2.5		٧	
Vон		$V_{CC} = 5 V$,	$I_{OH} = -3 \text{ mA}$	3			3		3			
VOH		V _{CC} = 4.5 V	$I_{OH} = -24 \text{ mA}$	2			2					
		VCC = 4.5 V	$I_{OH} = -32 \text{ mA}$	2*					2			
VOL		V _{CC} = 4.5 V	$I_{OL} = 48 \text{ mA}$			0.55		0.55			V	
VOL		VCC = 4.5 V	I _{OL} = 64 mA			0.55*				0.55		
V _{hys}					100						mV	
١,	Control inputs	V _{CC} = 5.5 V,	V _I = V _{CC} or GND			±1		±1		±1	μΑ	
ΙΙ	A or B ports	VCC = 3.5 V,	AL = ACC OLGIAD			±100		±100		±100	μΑ	
lozh‡		$V_{CC} = 5.5 \text{ V},$	$V_0 = 2.7 \text{ V}$			50		50		50	μΑ	
lozL [‡]		$V_{CC} = 5.5 \text{ V},$	$V_0 = 0.5 V$			-50		– 50		-50	μΑ	
I _{off}		$V_{CC} = 0$,	V_I or $V_O \le 4.5 \text{ V}$			±100	1	ζ.		±100	μΑ	
ICEX		V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high			50	2700	50		50	μΑ	
IO§		V _{CC} = 5.5 V,	V _O = 2.5 V	-50	-100	-180	– 50	-180	-50	-180	mA	
			Outputs high		5	250		250		250	μΑ	
ICC	A or B ports IO		Outputs low		24	30		30		30	mA	
				$V_I = V_{CC}$ or GND	Outputs disabled		0.5	250		250		250
	Data inputs	V _{CC} = 5.5 V, One input at 3.4 V,	Outputs enabled			1.5		1.5		1.5		
ΔI_{CC}^{\P}		Other inputs at VCC or GND	Outputs disabled			0.05		0.05		0.05	mA	
	Control inputs	V_{CC} = 5.5 V, One input at 3.4 V, Other inputs at V_{CC} or GND				1.5		1.5		1.5		
Ci	Control inputs	V _I = 2.5 V or 0.5 V			4						pF	
C _{io}	A or B ports	$V_0 = 2.5 \text{ V or } 0.5 \text{ V}$			7						pF	

^{*} On products compliant to MIL-PRF-38535, this parameter does not apply.

[†] All typical values are at $V_{CC} = 5 \text{ V}$.

[‡] The parameters IOZH and IOZL include the input leakage current.

[§] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

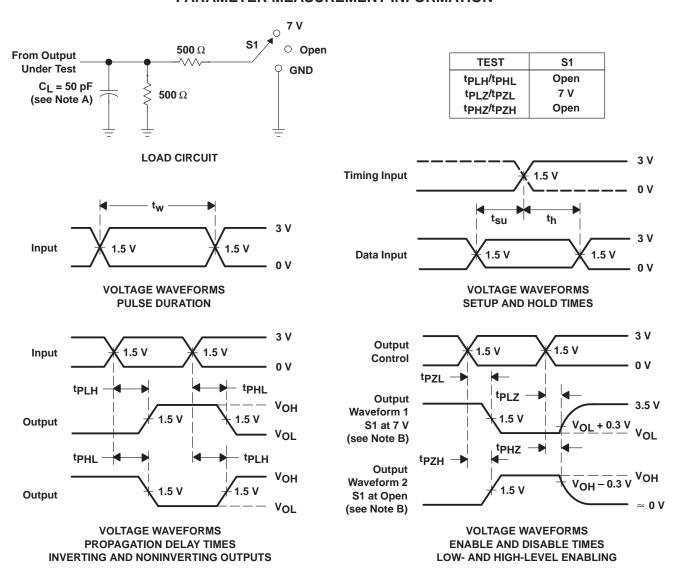
[¶] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C		SN54ABT620		SN74ABT620		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
^t PLH	A or B	B or A	1	4.1	1		1	4.8	ns
^t PHL	AOIB		1	4.3	1	4	1	4.8	
^t PZH	OEBA	А	1.3	4.6	1.3	1/4	1.3	5.5	ns
^t PZL		^	1	6.1	1	2/2	1	7.1	115
^t PHZ	ОЕВА	А	2	6.3	2		2	7	ns
t _{PLZ}		A	1.4	5.4	1.4		1.4	5.8	116
^t PZH	OEAB	В	1.6	6.2	1.6		1.6	6.8	
^t PZL			2	5.9	2		2	6.4	ns
^t PHZ	OEAB	В	1.2	5.6	1.2		1.2	6.5	no
t _{PLZ}		ט	1.1	4.7	1.1		1.1	5.6	ns

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r \leq 2.5$ ns, $t_f \leq 2.5$ ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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